

# DATA SHEET

## **BFQ241** PNP video transistor

Product specification  
Supersedes data of 1995 Oct 09  
File under Discrete Semiconductors, SC05

1996 Sep 04

## PNP video transistor

## BFQ241

## APPLICATIONS

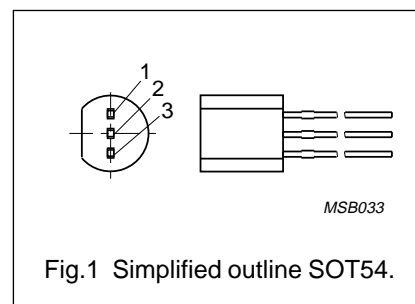
- Primarily intended for buffer stages in high resolution colour monitors.

## DESCRIPTION

PNP silicon transistor encapsulated in a 3-lead plastic SOT54 package.

## PINNING

PIN	DESCRIPTION
1	base
2	collector
3	emitter



## QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS	TYP	MAX	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	–100	V
$I_C$	collector current (DC)		–	–100	mA
$P_{tot}$	total power dissipation	up to $T_s = 60\text{ °C}$	–	1.15	W
$f_T$	transition frequency	$I_C = -25\text{ mA}$ ; $V_{CE} = -10\text{ V}$	1	–	GHz
$C_{re}$	feedback capacitance	$I_C = 0$ ; $V_{CB} = -10\text{ V}$	1.7	–	pF
$T_j$	junction temperature		–	150	°C

## LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

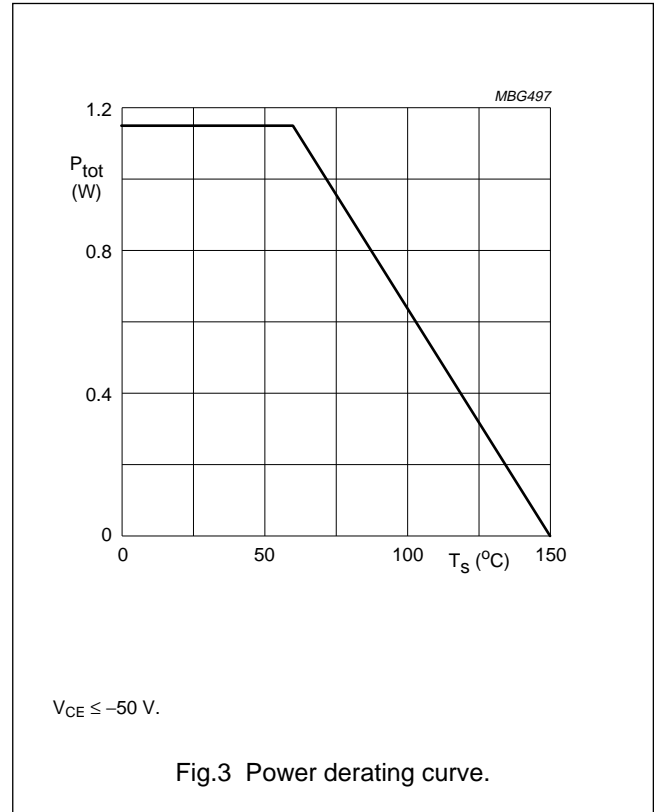
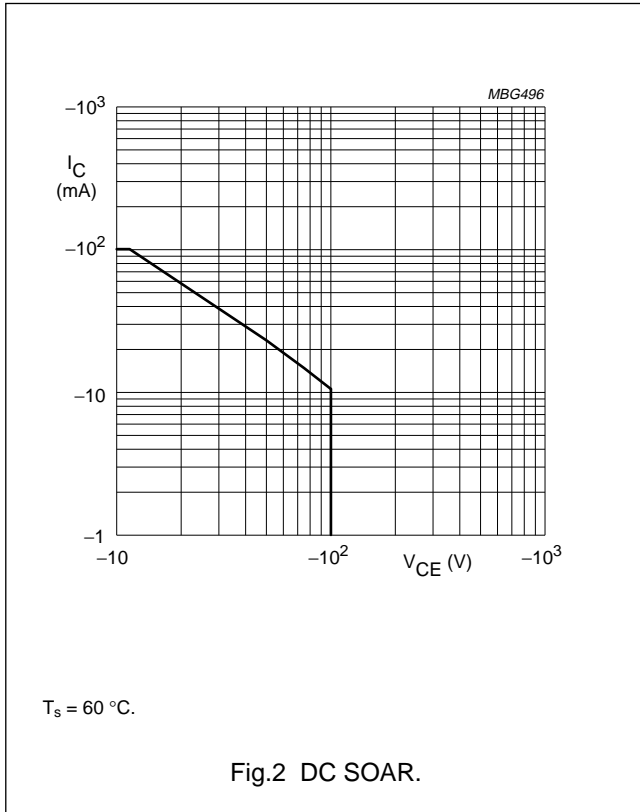
SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
$V_{CBO}$	collector-base voltage	open emitter	–	–100	V
$V_{CER}$	collector-emitter voltage	$R_{BE} = 100\ \Omega$	–	–95	V
$V_{EBO}$	emitter-base voltage	open collector	–	–3	V
$I_C$	collector current (DC)	see Fig.2	–	–100	mA
$I_{C(AV)}$	average collector current	see Fig.2	–	–100	mA
$P_{tot}$	total power dissipation	up to $T_s = 60\text{ °C}$ ; note 1; see Fig.3	–	1.15	W
$T_{stg}$	storage temperature		–65	+150	°C
$T_j$	junction temperature		–	150	°C

## Note

- $T_s$  is the temperature at the soldering point of the collector pin.

PNP video transistor

BFQ241



**THERMAL CHARACTERISTICS**

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-s}$	thermal resistance from junction to soldering point	$P_{tot} = 1.15\ W$ ; up to $T_s = 60\ ^\circ C$ ; note 1	78	K/W

**Note**

- $T_s$  is the temperature of the soldering point of the collector pin.

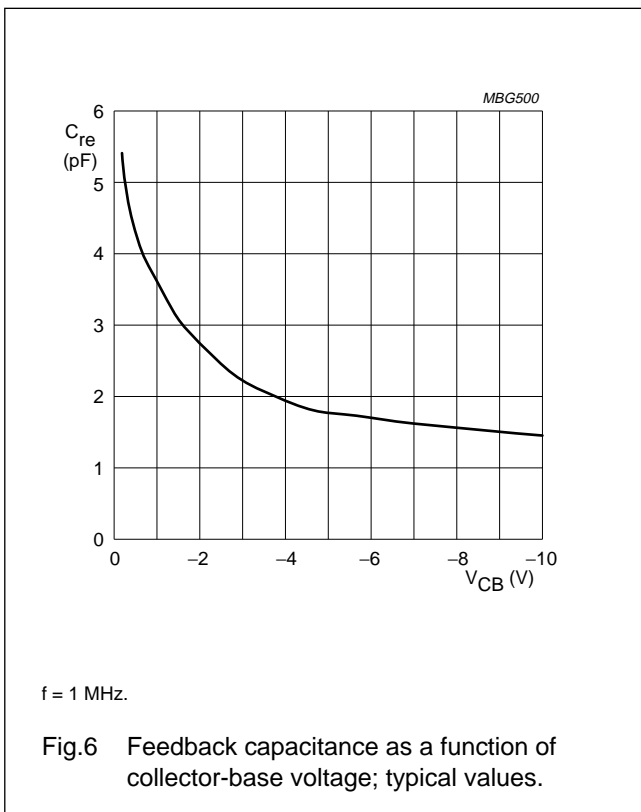
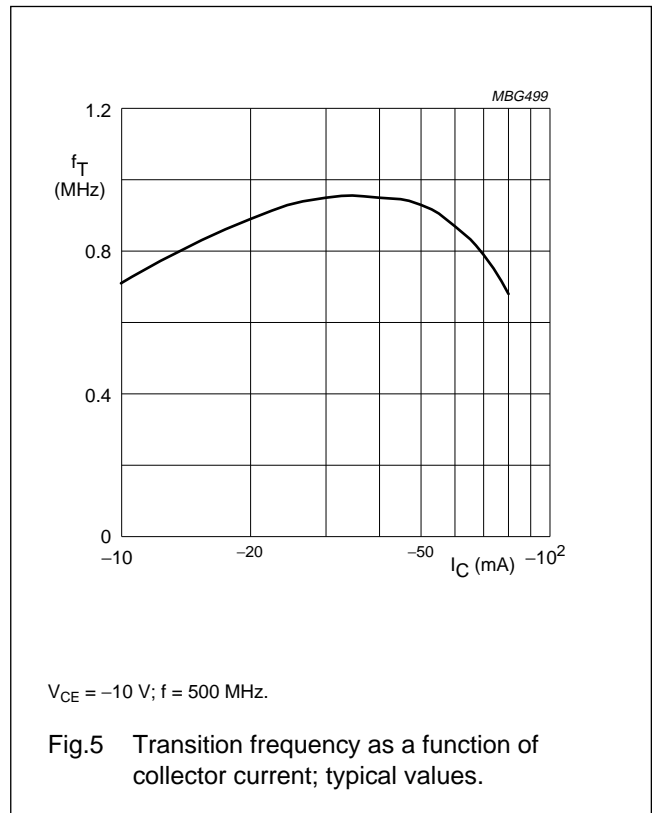
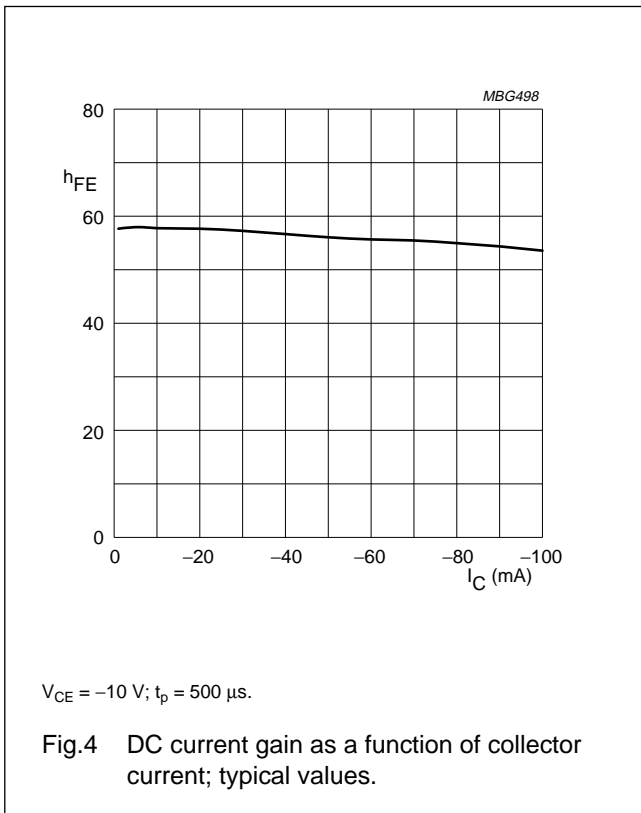
**CHARACTERISTICS**

$T_j = 25\ ^\circ C$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -0.1\ mA$ ; $I_E = 0$	-100	-	-	V
$V_{(BR)CER}$	collector-emitter breakdown voltage	$I_C = -1\ mA$ ; $R_{BE} = 100\ \Omega$	-95	-	-	V
$V_{(BR)EBO}$	emitter-base breakdown voltage	$I_C = 0$ ; $I_E = -0.1\ mA$	-3	-	-	V
$I_{CES}$	collector-emitter leakage current	$V_{CE} = -50\ V$ ; $V_{BE} = 0$	-	-	-100	$\mu A$
$h_{FE}$	DC current gain	$I_C = -25\ mA$ ; $V_{CE} = -10\ V$ ; see Fig.4	20	-	-	
$f_T$	transition frequency	$I_C = -25\ mA$ ; $V_{CE} = -10\ V$ ; $f = 500\ MHz$ ; see Fig.5	-	1	-	GHz
$C_{re}$	feedback capacitance	$I_C = 0$ ; $V_{CB} = -10\ V$ ; $f = 1\ MHz$ ; see Fig.6	-	1.7	-	pF

PNP video transistor

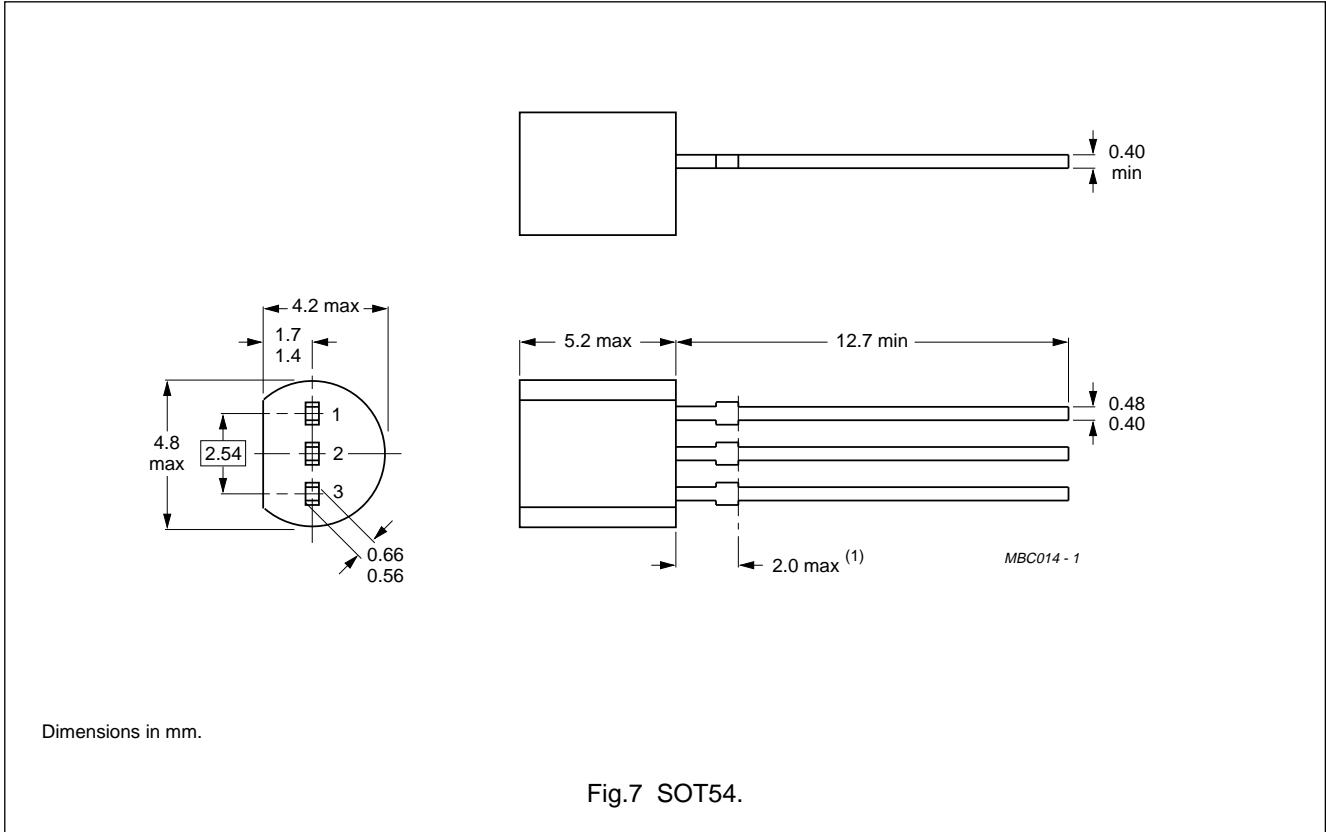
BFQ241



PNP video transistor

BFQ241

PACKAGE OUTLINE



## PNP video transistor

BFQ241

**DEFINITIONS**

<b>Data Sheet Status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

**LIFE SUPPORT APPLICATIONS**

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.